

Control of Magnetism with Oxide Hybrid Structures

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Magnetism



Oxide



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Acknowledgement



Prof. Ivan K. Schuller
Principal Investigator



Prof. Jose de la Venta
Thin Film, Magnetism



Dr. Thomas Saerbeck
Diffraction, Magnetism



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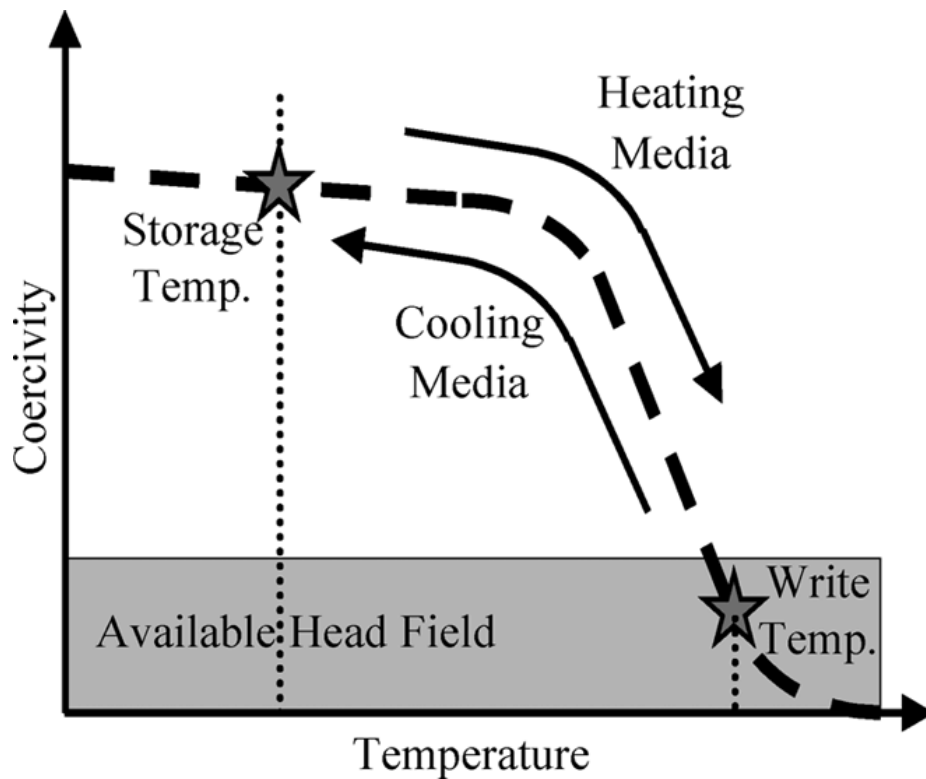
Siming Wang
Thin Film, Simulation,
Fabrication

Outline

- ***Introduction***
 - Review Control of Magnetism
 - Phase Transition in Vanadium Oxide (VO_x)
- ***Control of Magnetism with VO_x/FM***
 - Tuning with Magnetostrictive Effect
- ***Coercivity Enhancement in $\text{V}_2\text{O}_3/\text{Ni}$***
 - Competing Length Scales on Nanoscale
- ***Summary and Outlook***

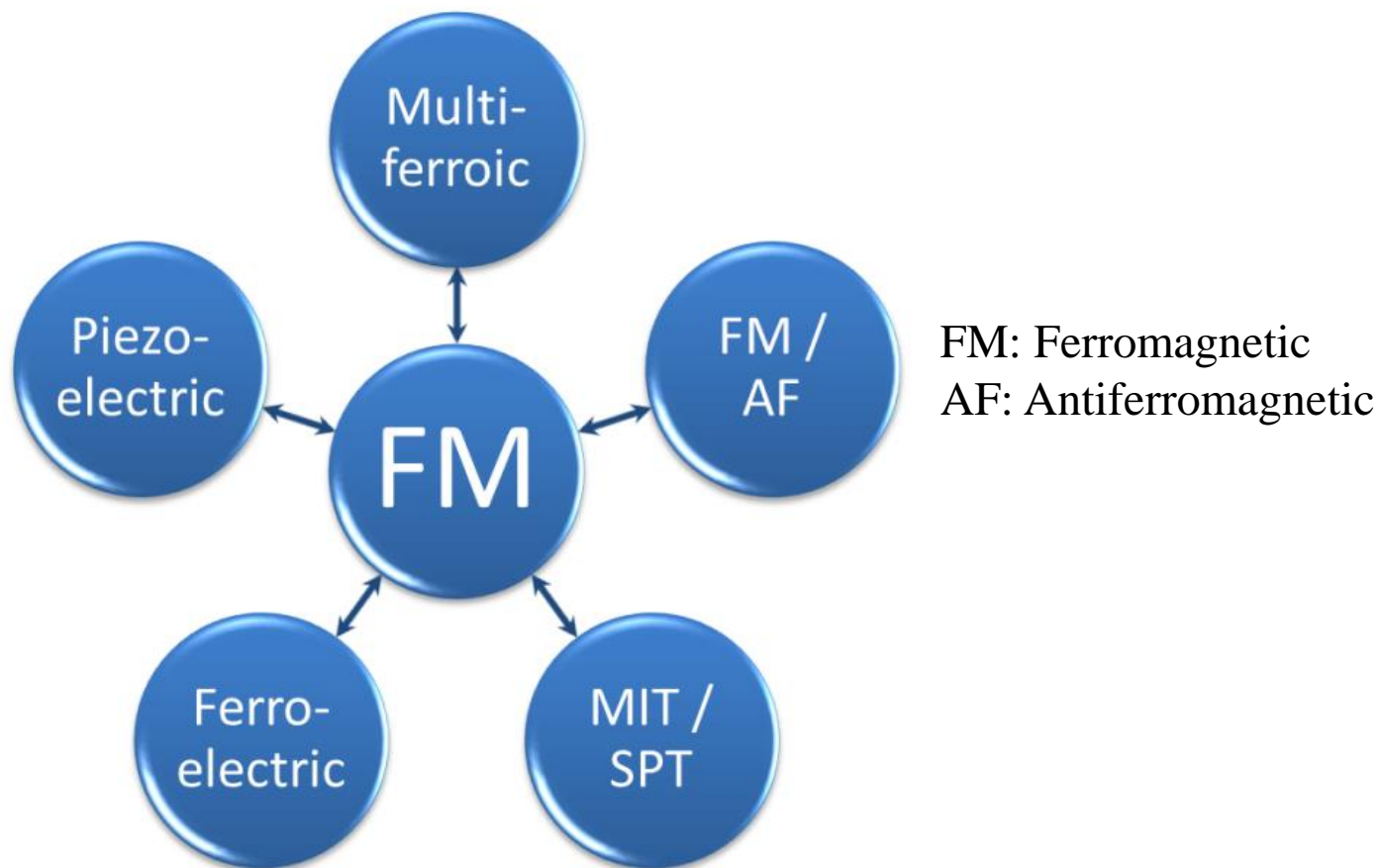
Control of Magnetism

Heat Assisted Magnetic Recording (HAMR)



- Microwave Assisted
- Acoustic Phonon Assisted
- Ultrafast Laser Induced

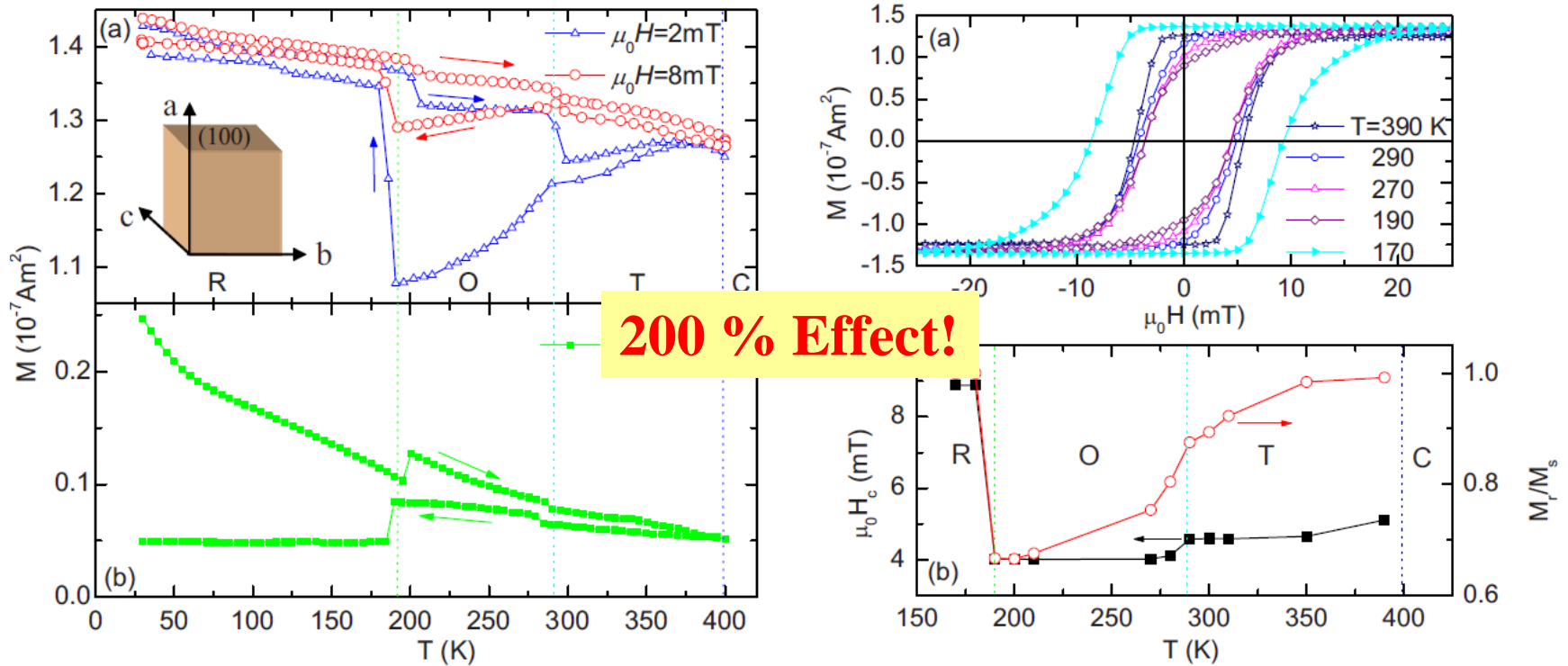
“Sun-Wheel” of Oxide Hybrid Structures



T. Saerbeck, J. de la Venta, S. Wang, J. G. Ramirez, M. Erekhinsky, I. Valmianski, I. K. Schuller, J. Mater. Res., Invited Review (2014)

Control of Magnetism with SPT

BaTiO₃/Fe Bilayer: Control through Interface Strain Coupling

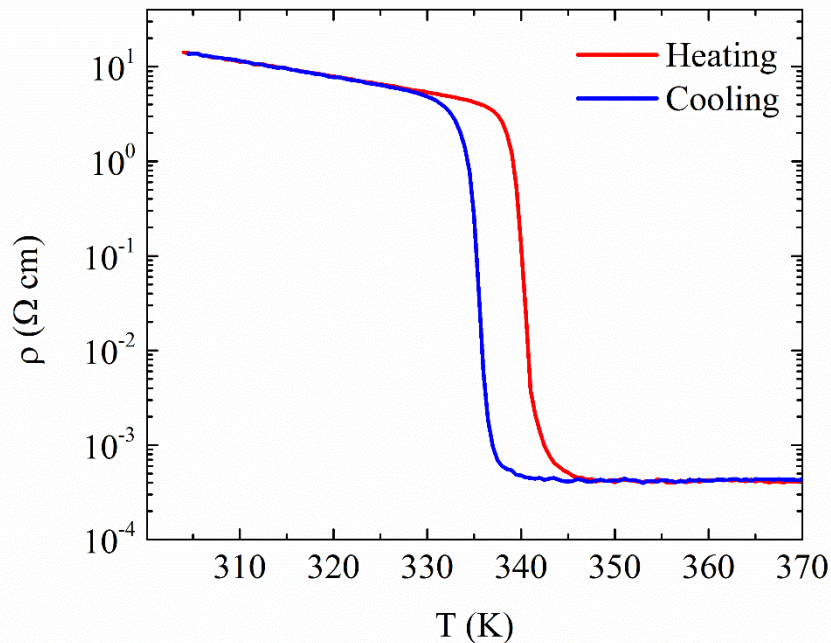


S. Sahoo *et al.*, Phys. Rev. B **76**, 092108 (2007)

Phase Transition in VO₂

MIT

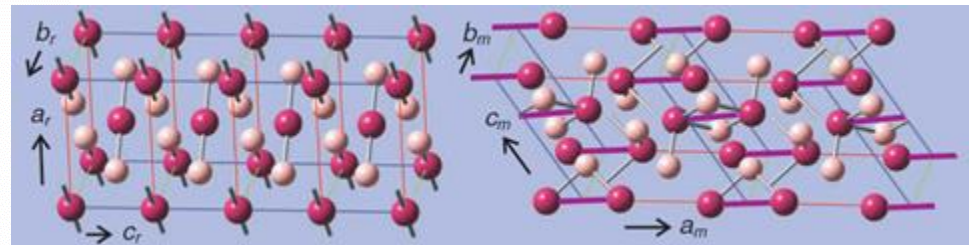
SPT



$$T_C = 340 \text{ K}$$

High-T Rutile

Low-T Monoclinic



P. Baum *et al.*, Science **318**, 788 (2007)

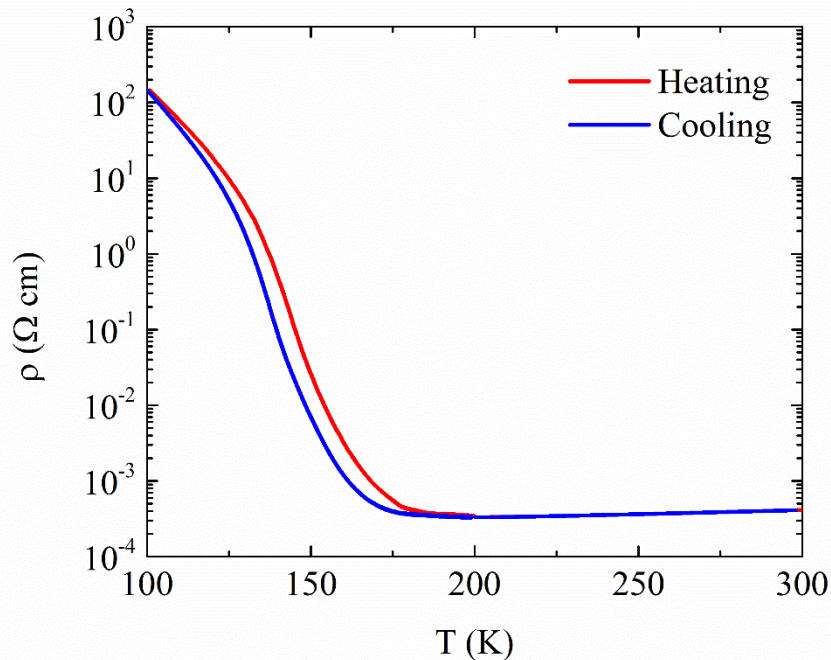
~ 1 % Lattice Distortion

~ 1 % Volume Change

Phase Transition in V_2O_3

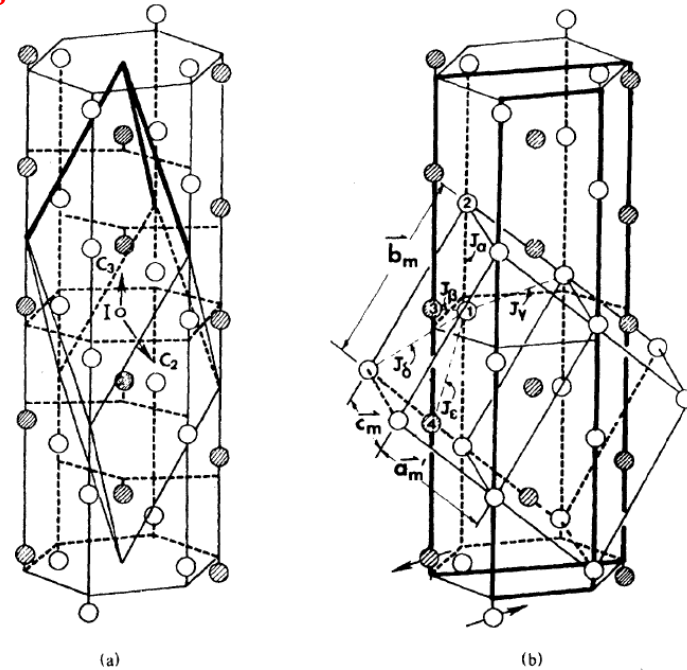
MIT

SPT



$$T_C = 150 - 165 \text{ K}$$

High-T Rhombohedral Low-T Monoclinic



R. E. Word *et al.*, Phys. Rev. B **23**, 3533 (1981)

$\sim 1\%$ Lattice Distortion

$\sim 1\%$ Volume Change

Why VO_x ?

- First Order Phase Transition

Abrupt Structural Change in **Narrow** Temperature Range

- Choice of Transition Temperatures

$$T_C(\text{VO}_2) = 340 \text{ K}, T_C(\text{V}_2\text{O}_3) = 150 - 165 \text{ K}$$

- Multiple Driving Forces to Induce SPT

Temperature, Voltage/Current, Light, Gating, Pressure, etc.

Outline

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- *Control of Magnetism with VO_x/FM*

- Tuning with Magnetostrictive Effect

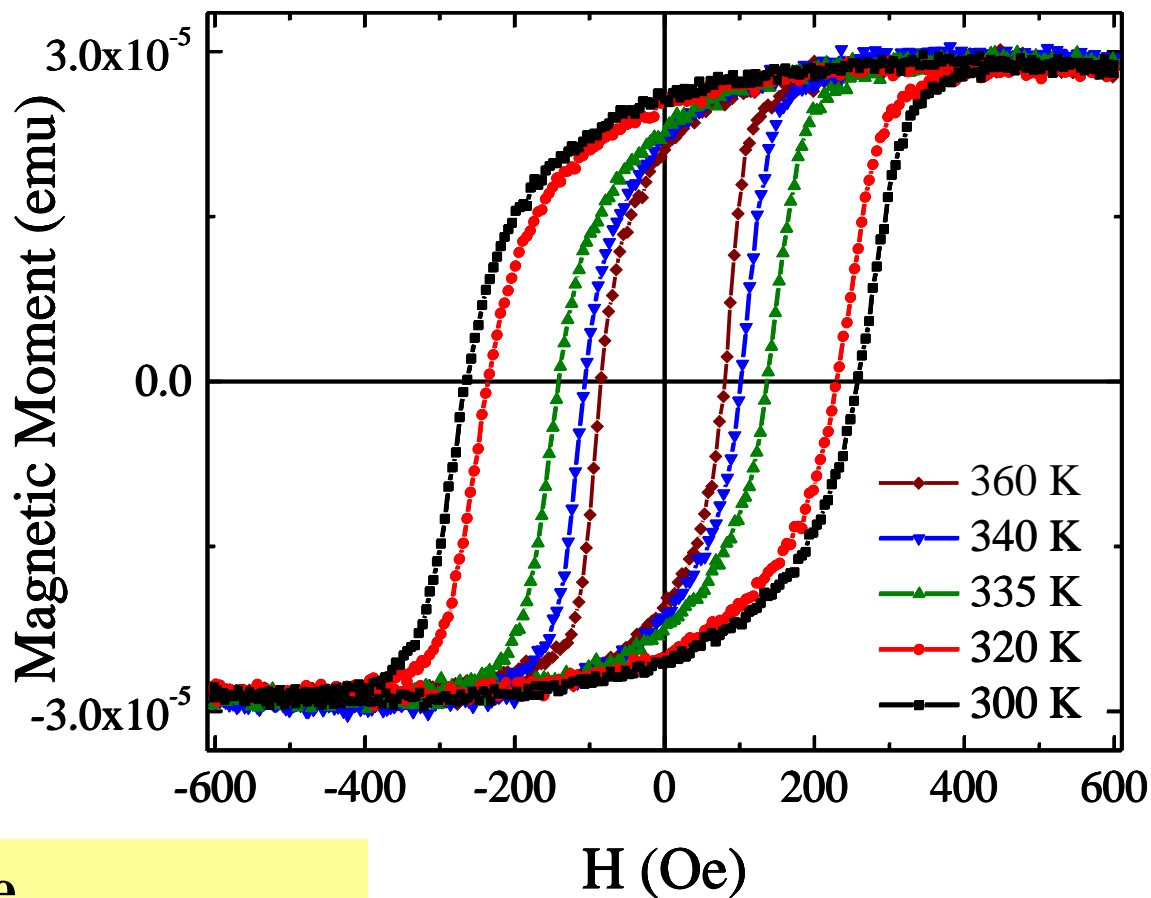
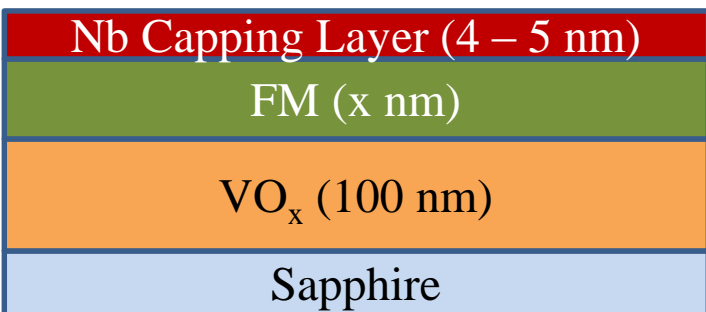
- *Coercivity Enhancement in $\text{V}_2\text{O}_3/\text{Ni}$*

- Competing Length Scale on Nanoscale

- *Conclusions*

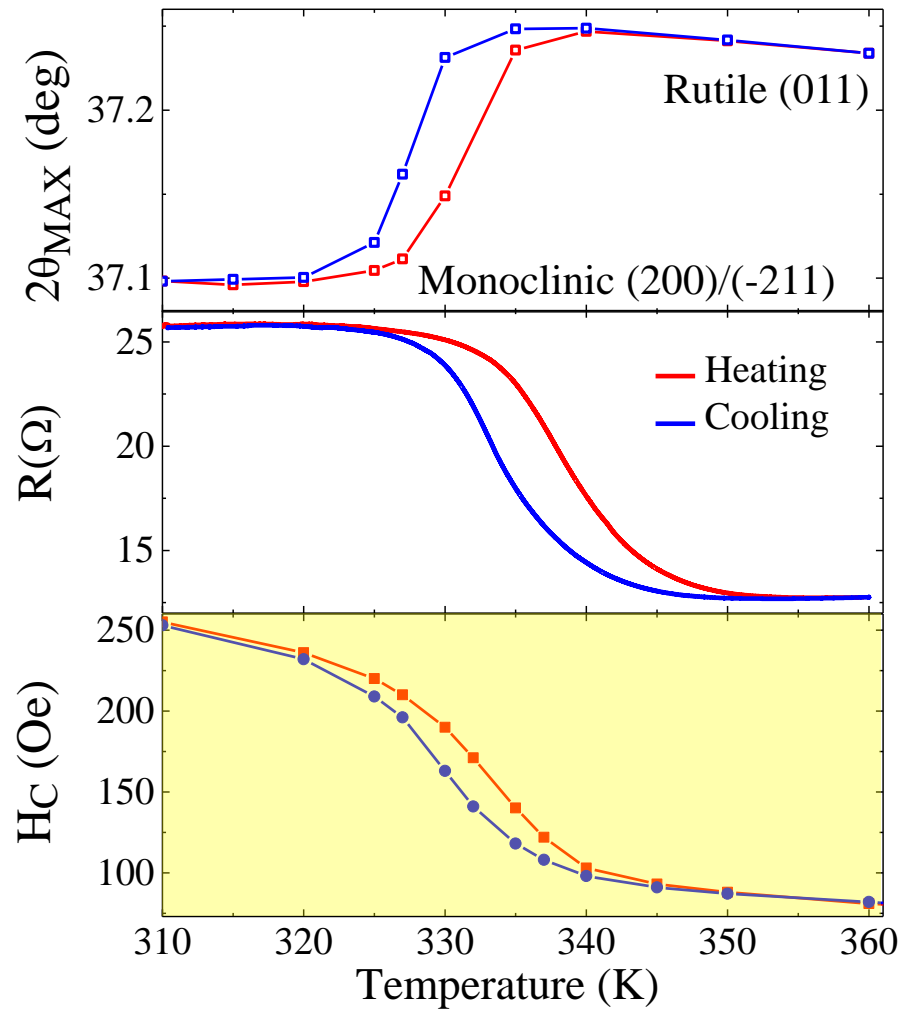
VO₂ / Ni

100 nm VO₂ / 10 nm Ni



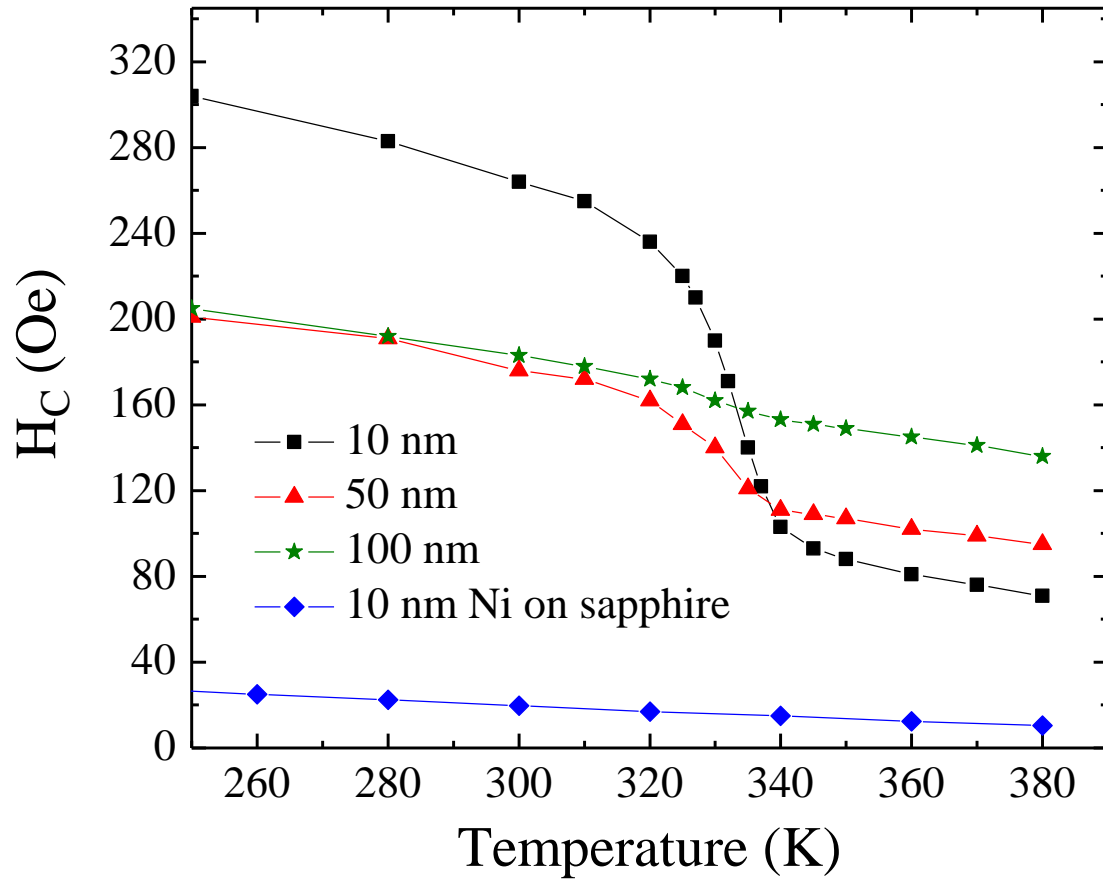
200 % Coercivity Change
across VO₂ Phase Transition at 340 K

Correlation: Phase Transition & Magnetism



Temperature Dependence & Thermal Hysteresis of H_C Coincide with MIT & SPT of VO_2

Ni Thickness Dependence



Effect **Reduces** as Ni Thickness **Increases**



Interface Effect

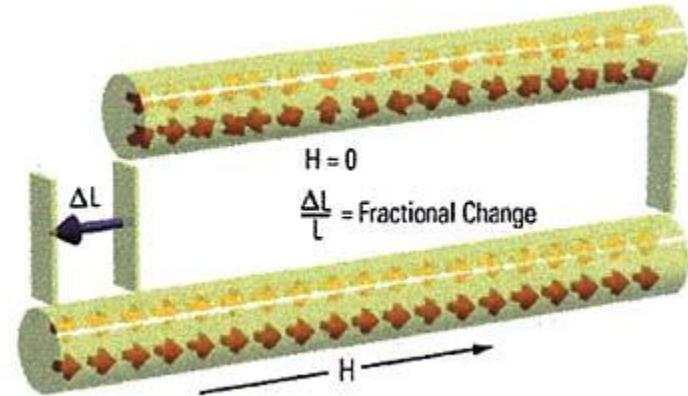
Magnetostriction

Change of Dimensions in the Applied Field Direction

Magnetostriction Coefficient $\lambda = \frac{\Delta L}{L}$

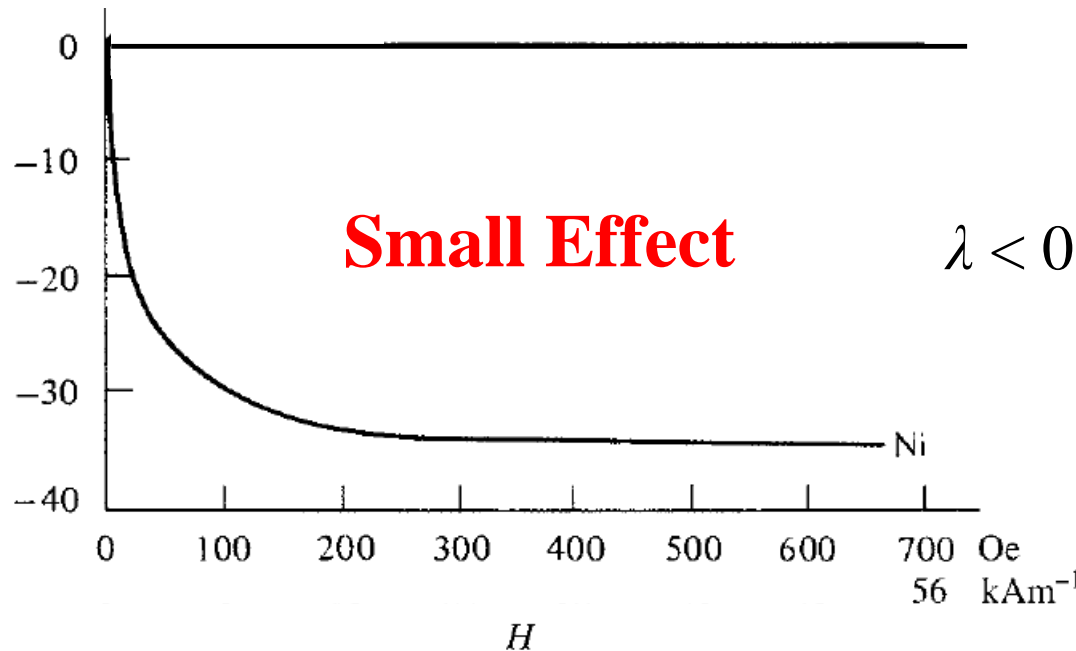
$\lambda < 0$ Contracts when Magnetized

$\lambda > 0$ Elongates when Magnetized



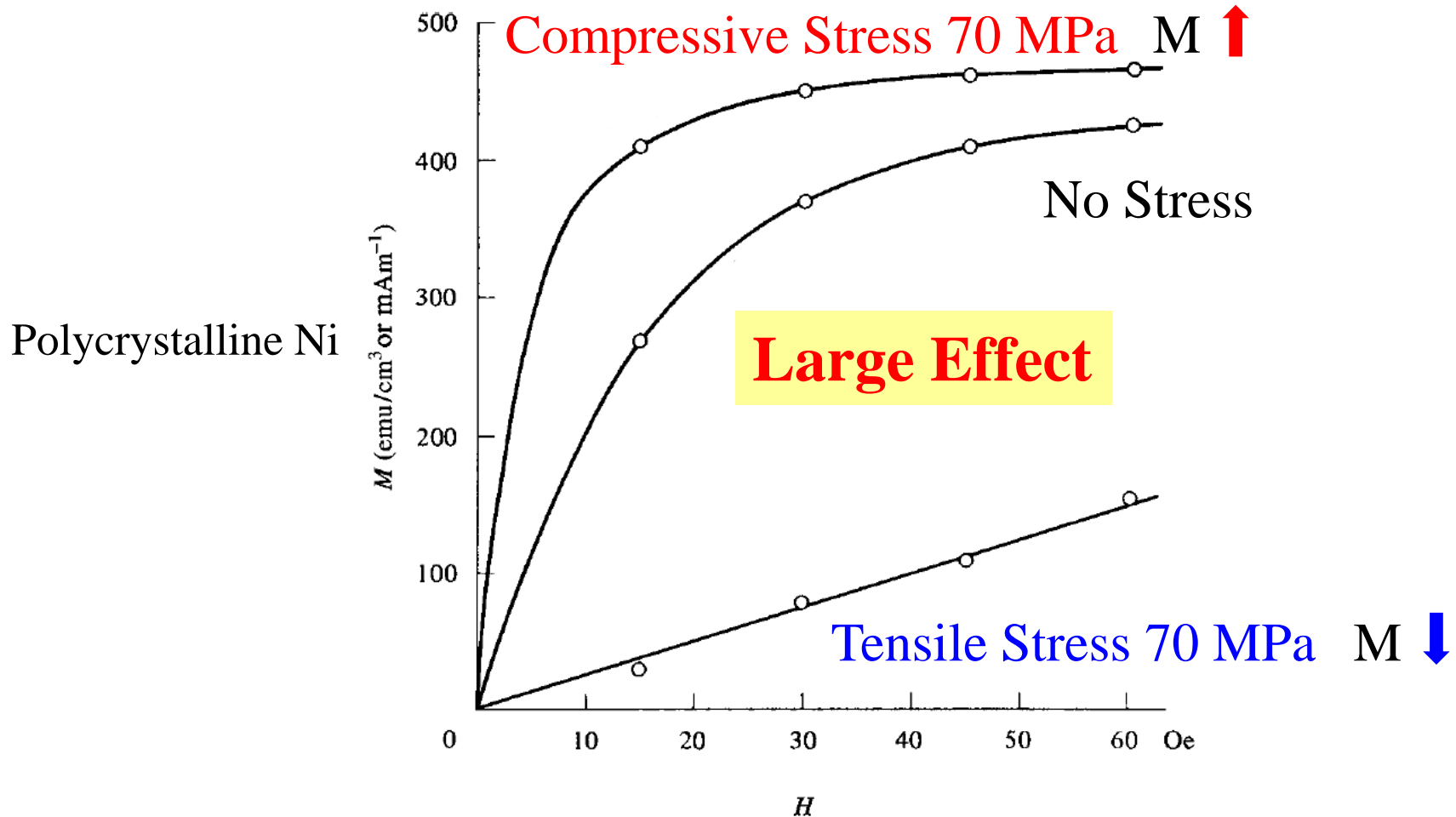
Polycrystalline Ni λ

(10^{-6})



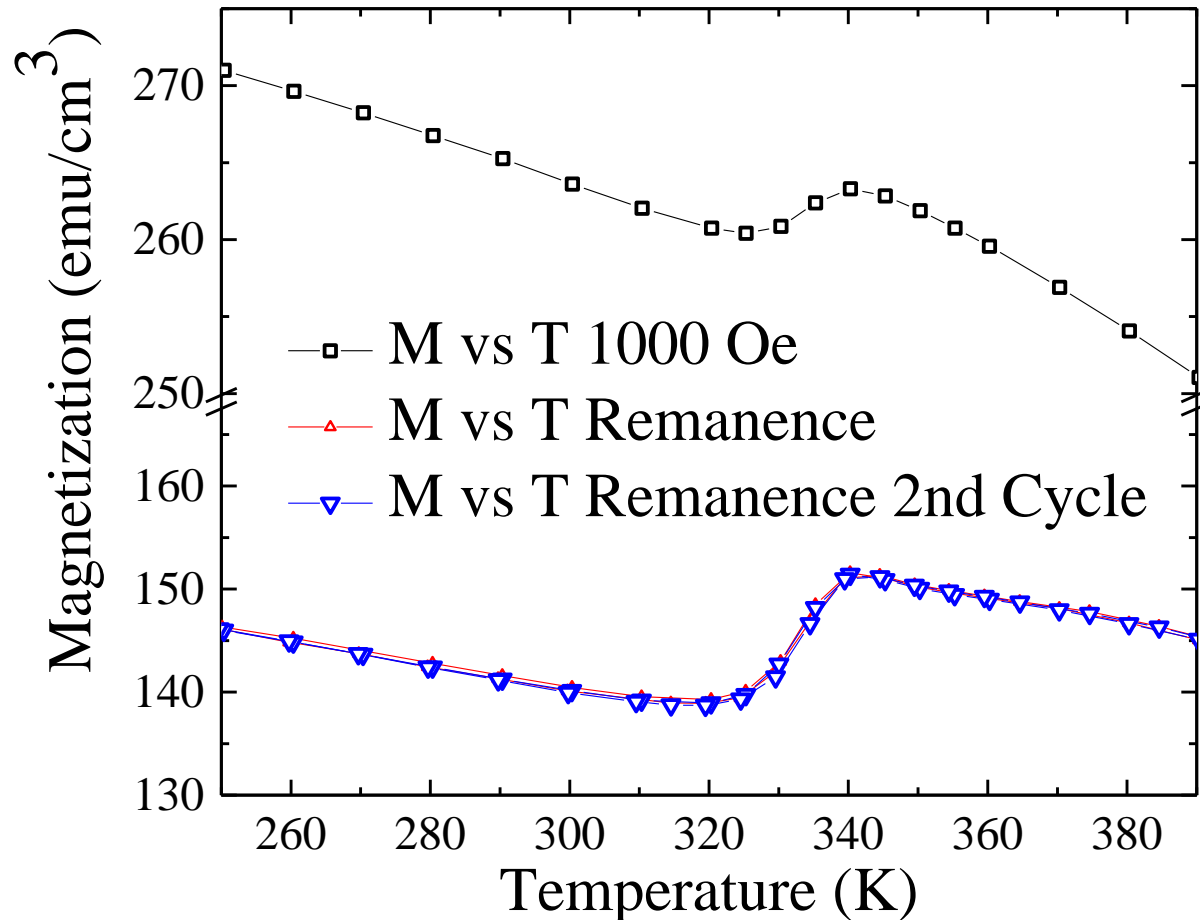
Inverse Magnetostriction

Change of Magnetization due to Applied Stress



Magnetization vs. Temperature

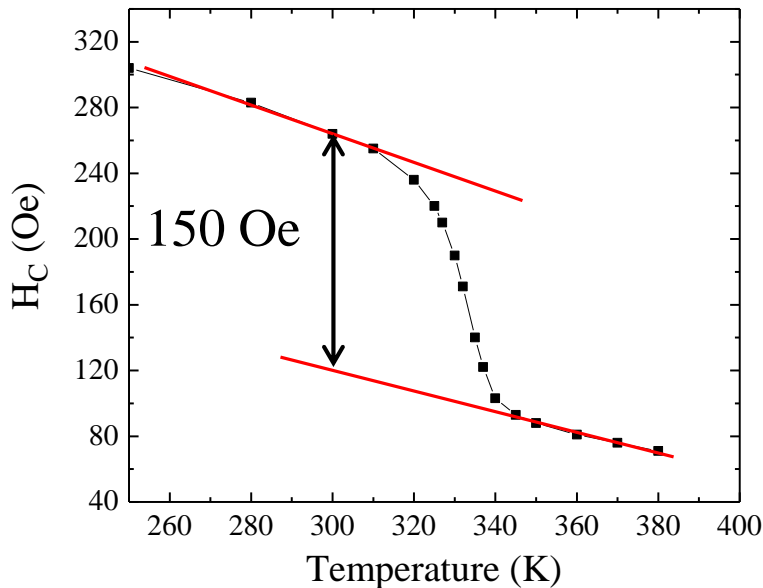
100 nm VO₂ / 10 nm Ni



Magnetic Domain Dynamics

Stress Anisotropy

100 nm VO₂ / 10 nm Ni



Stress Anisotropy Field

$$H_{K\sigma} = \frac{3\lambda\sigma}{M_S}$$

$$M_S = 470 \text{ emu/cm}^3$$

$$\lambda = -34 \times 10^{-6} \text{ Polycrystalline Ni}$$

➔ $\sigma \sim 59 \text{ MPa}$

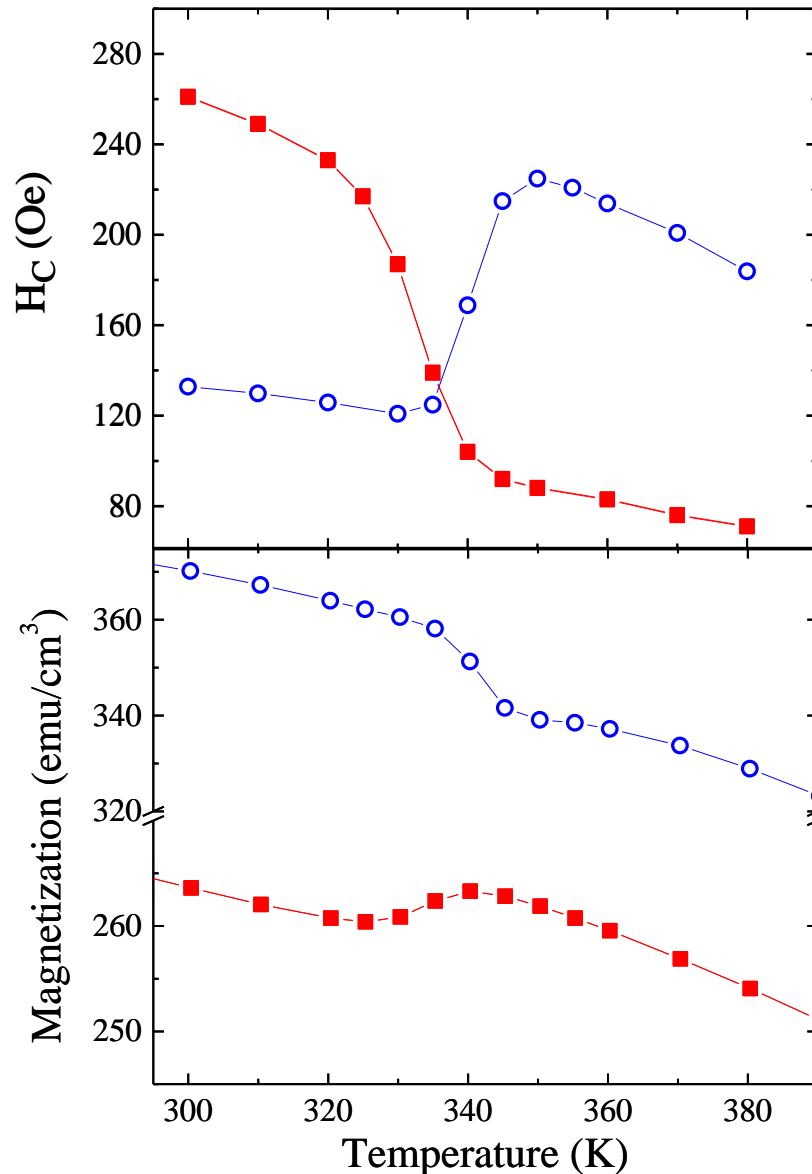
Stress Measured in VO₂ Films $\sigma \sim 400 \text{ MPa}$

B. Viswanath *et al.*, Scr. Mater. **64**, 490 (2011)

Tailoring the Effect

- Ni Deposited at 420 K
→ VO₂ Rutile
- Ni Deposited at RT
→ VO₂ Monoclinic

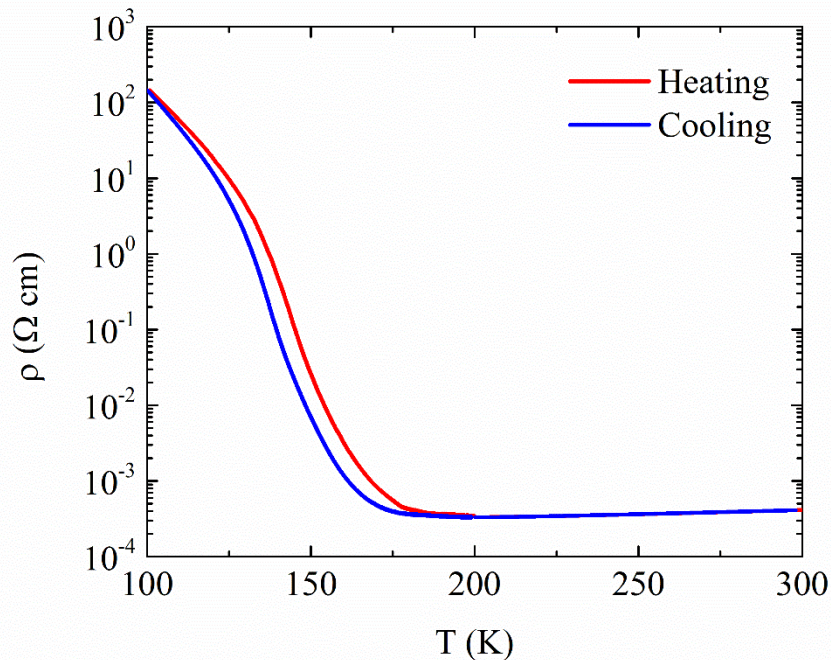
Reverse the Effect by
Selecting the Deposition
Temperatures, i.e. VO₂
Structures



Phase Transition in V_2O_3

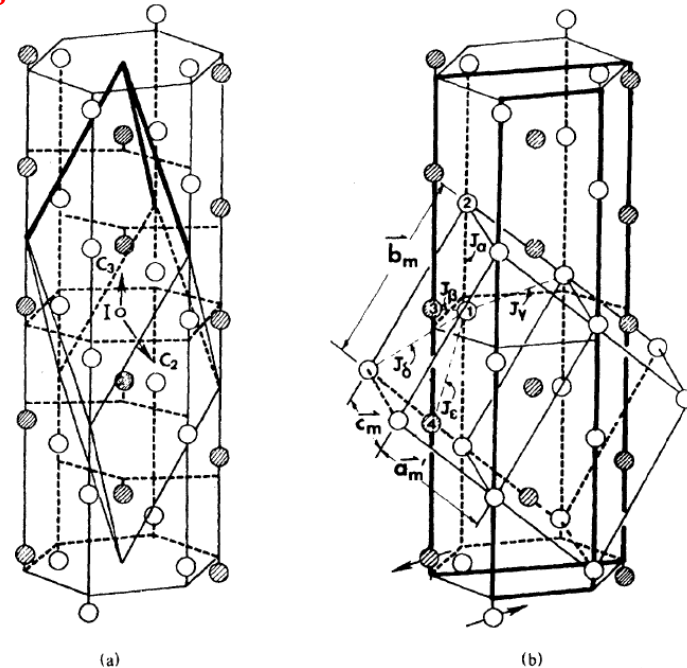
MIT

SPT



$$T_C = 150 - 165 \text{ K}$$

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R. E. Word *et al.*, Phys. Rev. B **23**, 3533 (1981)

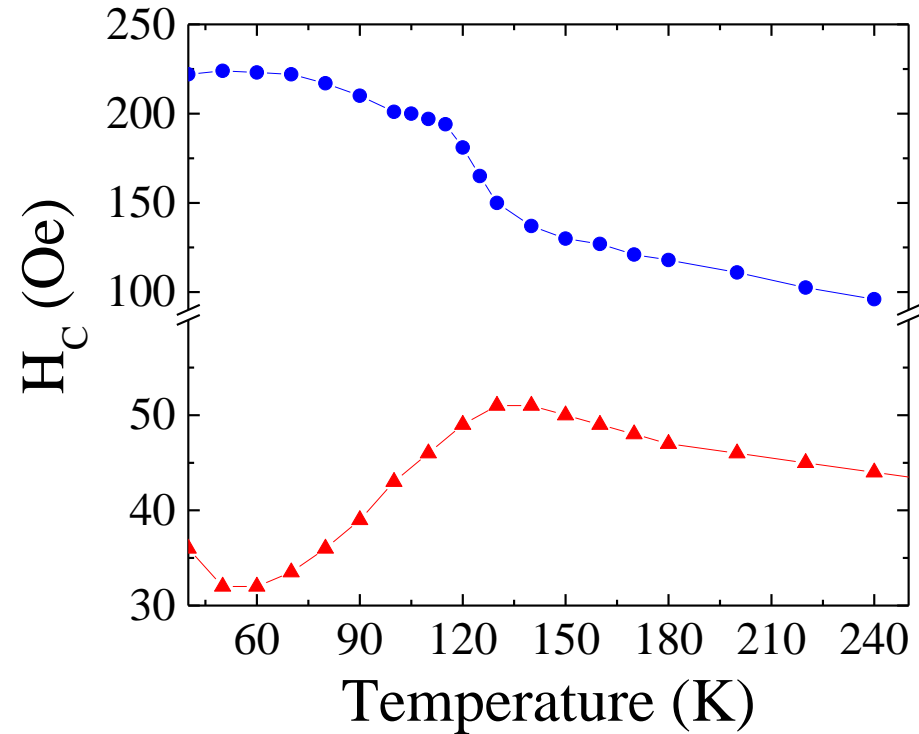
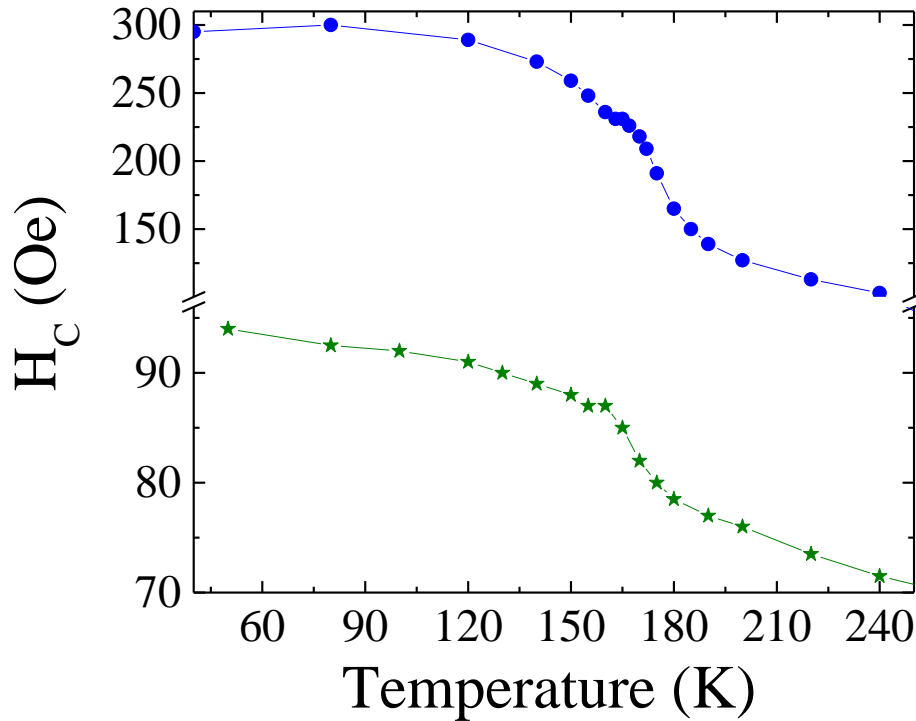
~ 1 % Lattice Distortion

~ 1 % Volume Change

V₂O₃ / FM: Generalization

100 nm V₂O₃ { 10 nm Ni
10 nm Co

100 nm V₂O₃ { 10 nm Ni
10 nm Fe



- Fe & Co Smaller Effect ← Smaller $\frac{\lambda}{M_S}$
- Fe Inverse Effect ← $\lambda_{Fe} > 0$

$$H_{K\sigma} = \frac{3\lambda\sigma}{M_S}$$

Control of Magnetism with VO_x/FM

- Control **Coercivity** & **Magnetization** with **SPT** of VO_x
- Interface Effect – **Reduces with Increasing FM Thickness**
- Tuning with Stress – **Choose Deposition Temperatures**
- Tuning with FM – **Choose λ & M_s**

J. de la Venta, S. Wang, J. G. Ramírez, and Ivan K. Schuller, Appl. Phys. Lett. **102**, 122404 (2013)

T. Saerbeck, J. de la Venta, S. Wang, J. G. Ramirez, M. Erekhinsky, I. Valmianski, I. K. Schuller, J. Mater. Res., Invited Review (2014)

I. K. Schuller, J. de la Venta, S. Wang, J. G. Ramirez, M. Erekhinsky, and A. Sharoni. Magnetic and Electrical Control of Engineered Materials. United States Patent 61/915,715, Issued December 13, 2013

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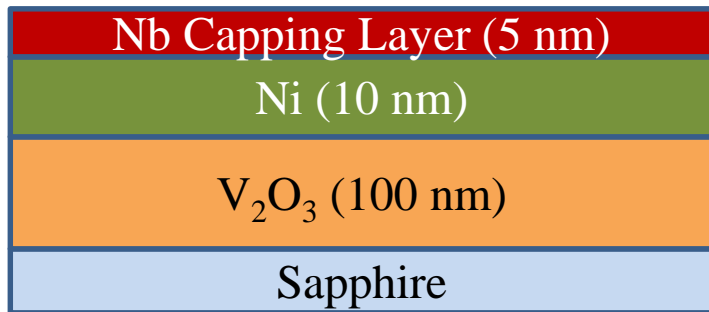
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- *Coercivity Enhancement in $\text{V}_2\text{O}_3/\text{Ni}$*

- Competing Length Scale on Nanoscale

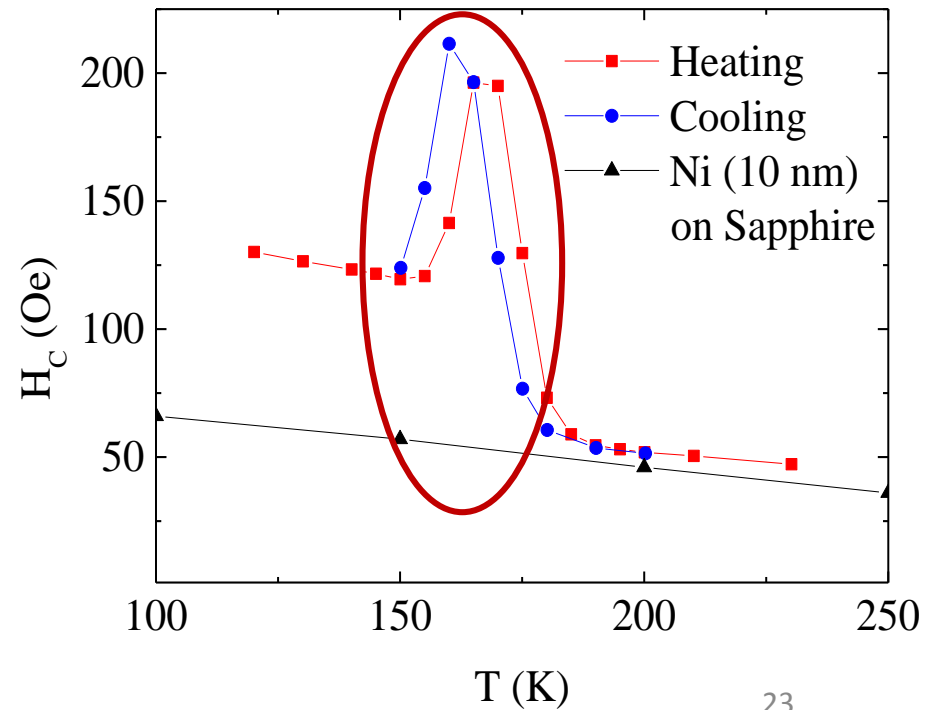
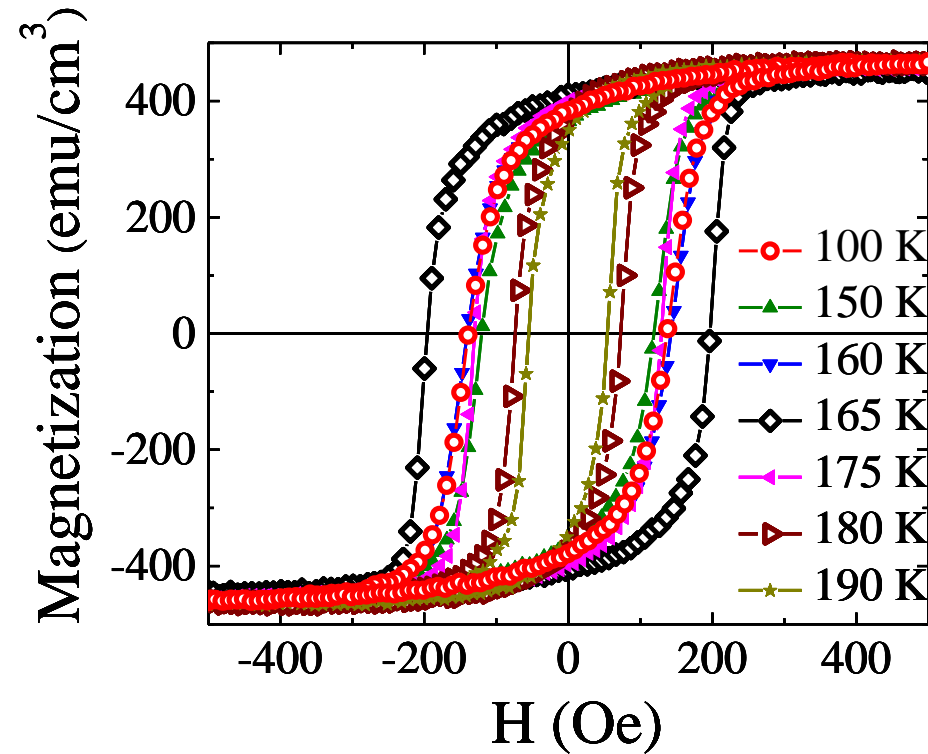
- *Conclusions*

V₂O₃/Ni

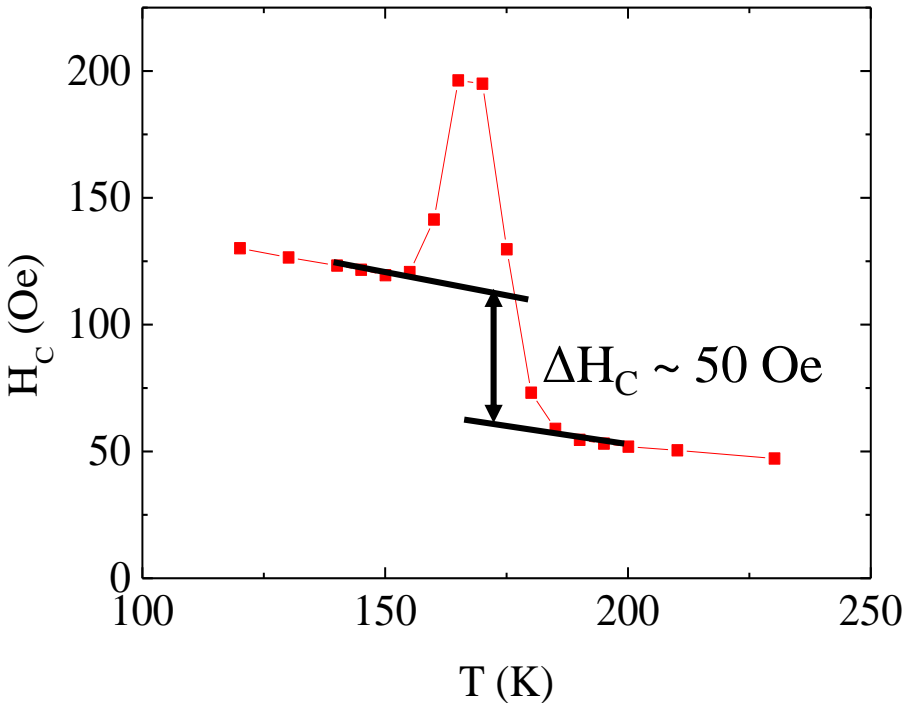


Peak at T_C = 150 – 165 K!

Coercivity Enhancement



Coercivity Enhancement



Structural Phase Transition in V_2O_3



Stress in Ni \sim 10's of MPa

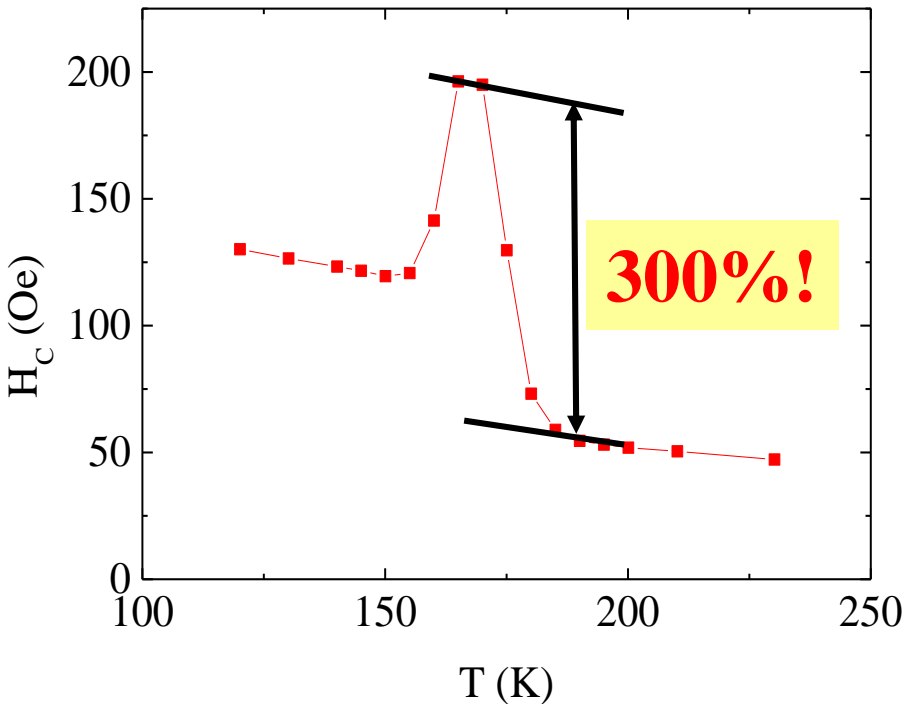


Stress Anisotropy Field \sim 50 Oe

J. de la Venta, S. Wang, J. G. Ramirez, and I. K. Schuller, Appl. Phys. Lett. **102**, 122404 (2013)

Coercivity Enhancement

What Reaches Maximum at $T = 165$ K in V_2O_3 ?



H_C Reaches Maximum at
 $T = 165$ K



Phase Coexistence in V_2O_3



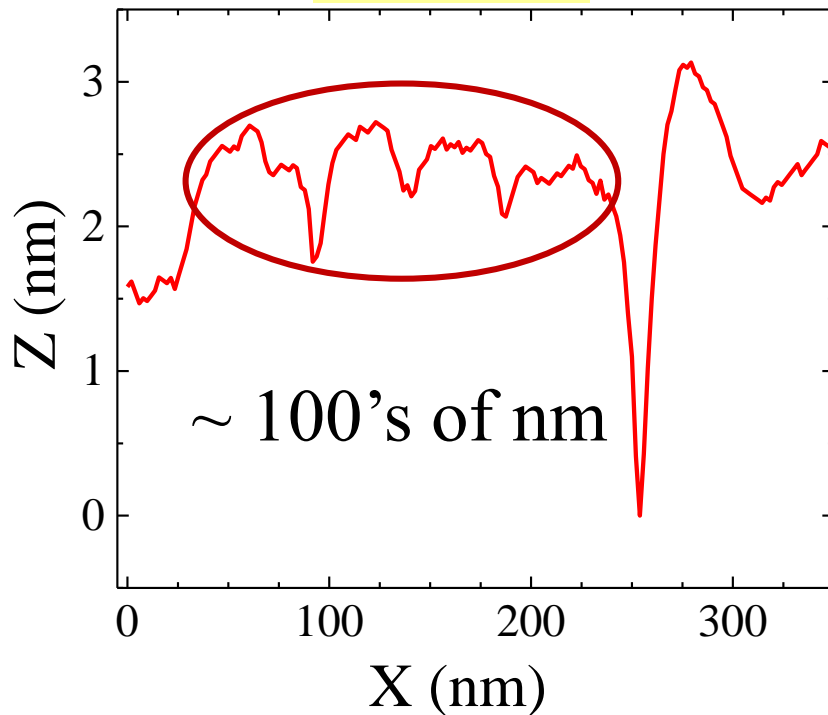
Single Phase Domain
 $\lambda_{V_2O_3} \leq 100$ nm

A. S. McLeod *et al.*, J49.00011, Cryogenic Infrared Nano-Imaging of the Metal-Insulator Transition in V_2O_3 , APS March Meeting, 2014

Competing Length Scales

Surface Morphology

Terraces



Magnetic Domain $d_{\text{Ni}} > 100$ nm

Single Phase Domain $\lambda_{\text{V}_2\text{O}_3} \leq 100$ nm

$$d_{\text{Ni}} > \lambda_{\text{V}_2\text{O}_3}$$



Phase Coexistence of V_2O_3



T-dependent Disorder

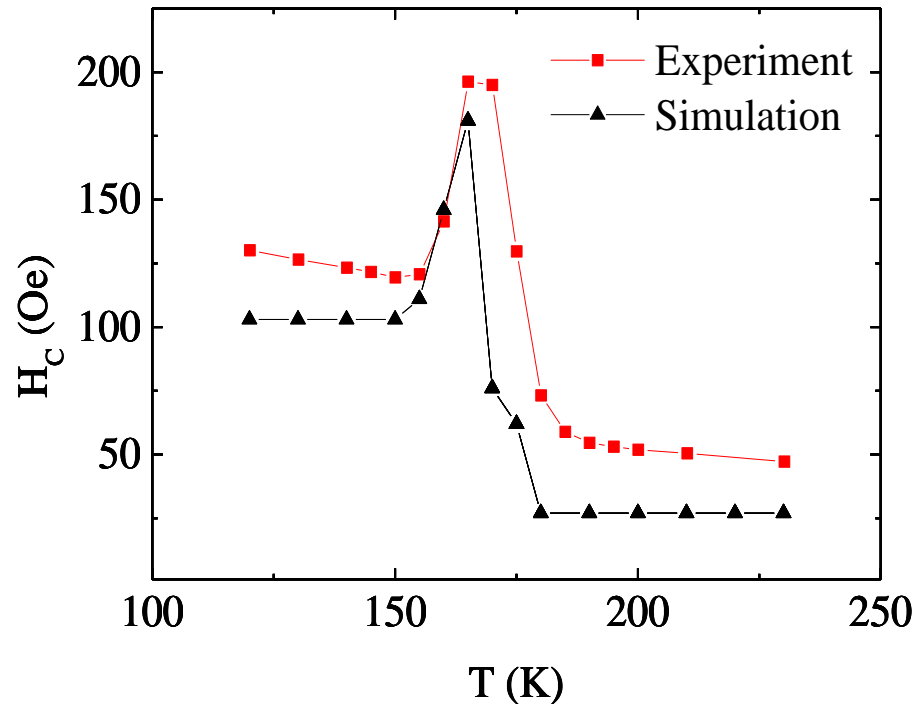


Enhanced Coercivity

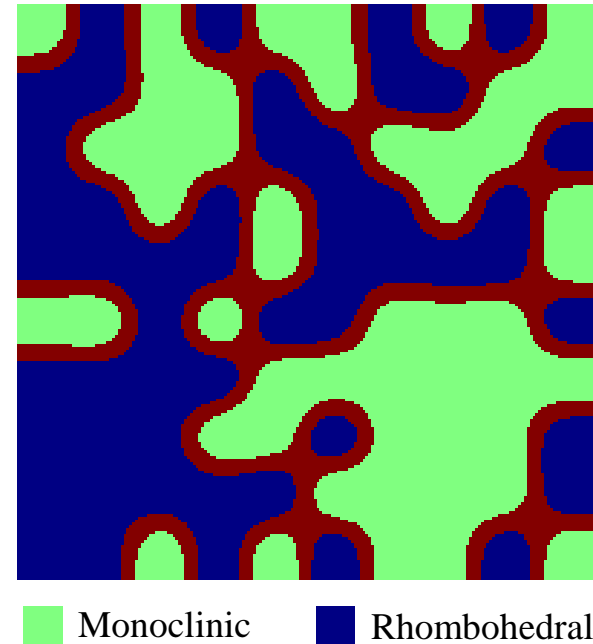
Micromagnetic Simulation

Ni

$V_2O_3: \lambda_{V_2O_3} = 100 \text{ nm}$
 $T = 165 \text{ K}$



1 μm^2



$$K_{\text{Stress}} = 1 \times 10^4 \text{ J/m}^3 \quad K_{\text{Pin}} = 4 \times 10^4 \text{ J/m}^3$$

25 – 30 nm Boundary

OOMMF, NIST

Gaussian Distribution of T_C

$T_C(\text{Mean}) = 165 \text{ K}$

Magnetization Reversal

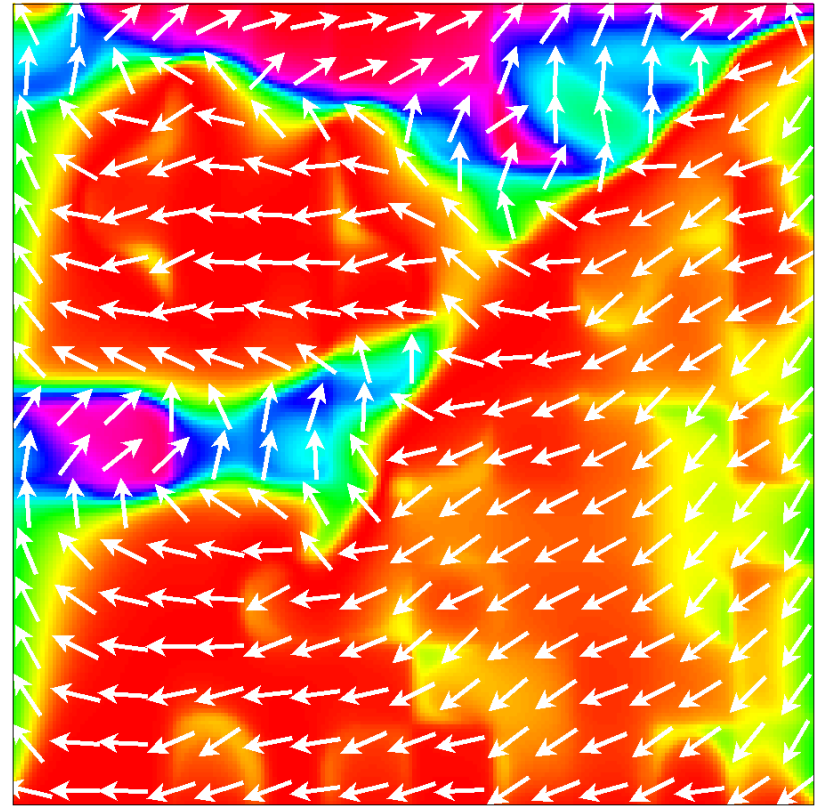
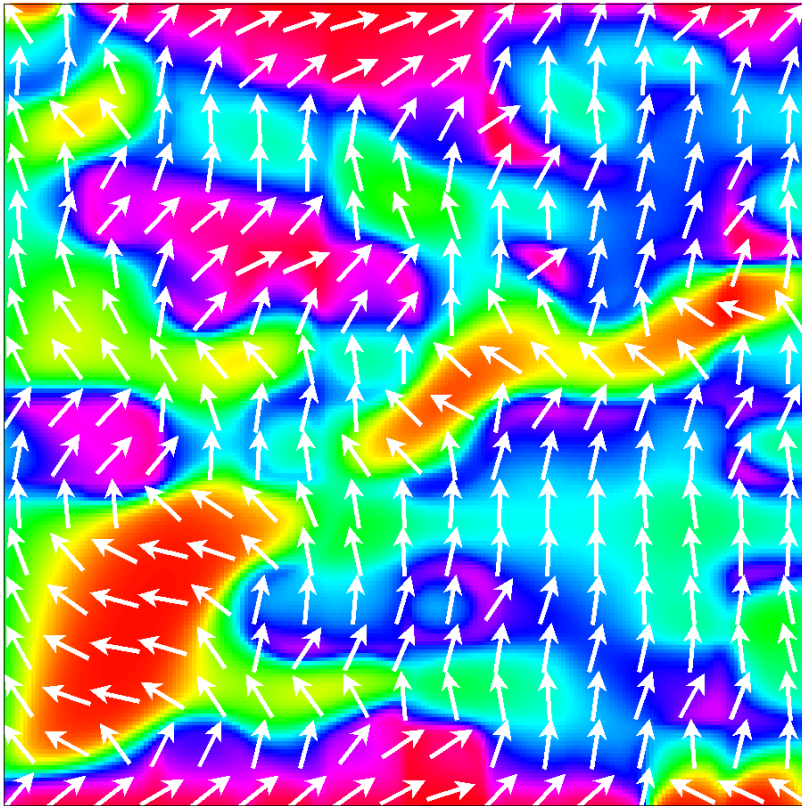
1 μm^2

165 K

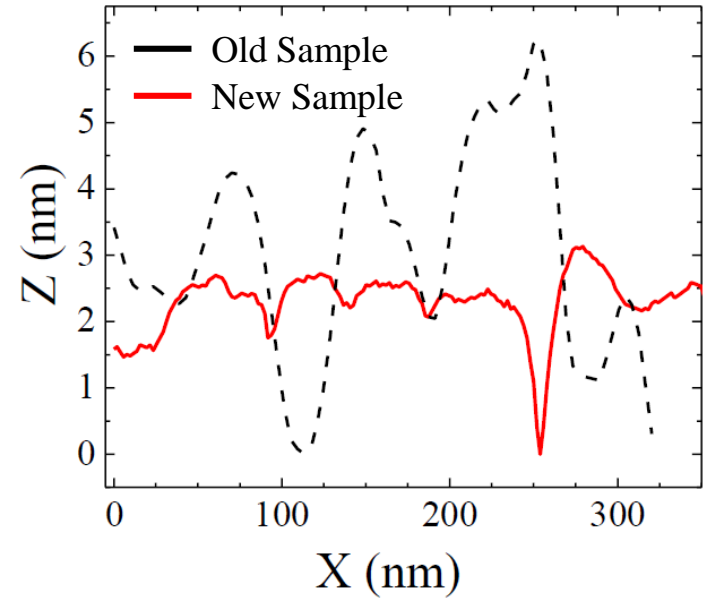
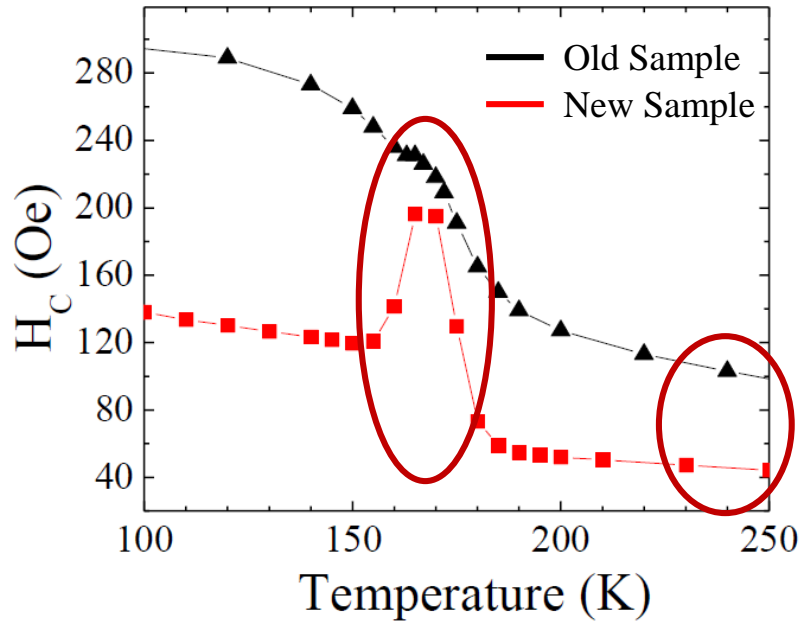
Before H_C

H \longleftrightarrow

After H_C



Microstructure Comparison



New Sample: 100's of nm Terraces (< 1 nm)

Old Sample: Higher Roughness (> 3 nm)



$$d_{\text{Ni}} > 100 \text{ nm}$$



$d_{\text{Ni}} > \lambda_{\text{V}_2\text{O}_3}$, Enhancement



$$d_{\text{Ni}} \sim 50 - 100 \text{ nm}$$



$d_{\text{Ni}} \approx \lambda_{\text{V}_2\text{O}_3}$, No Enhancement

Coercivity Enhancement in V_2O_3/Ni

- Magnetic Measurement – **Enhanced Coercivity** in V_2O_3/Ni
- Microstructure – **Competing Length Scales (d_{Ni} vs. $\lambda_{V_2O_3}$)**
- Model – **Phase Coexistence** Induced Pinning
- Simulation – **Quantitatively Reproduce** Enhanced Coercivity

J. de la Venta, S. Wang, T. Saerbeck, J. G. Ramírez, I. Valmianski, and Ivan K. Schuller, Appl. Phys. Lett. **104**, 062410 (2014)

T. Saerbeck, J. de la Venta, S. Wang, J. G. Ramirez, M. Erekhinsky, I. Valmianski, I. K. Schuller, J. Mater. Res., Invited Review (2014)

Summary

- First Order SPT – **Large Stress within a Narrow Temperature Range**
- Multiple Driving Forces to Induce SPT – **Temperature, Voltage/Current, Light, Gating, Pressure and etc.**
- Multiple Tuning Parameters – **Different FMs & Deposition Conditions**
- Competing Length Scales – **Disorder due to Nanoscale Inhomogeneity**

Outlook

- Probe V_2O_3 Domain – **Scanning Near-Field Optical Microscopy (SNOM)**
- Probe Magnetic Domain in Ni – **Neutron Scattering**
- Coercivity Enhancement with VO_2 – **Smooth Surface** (TiO₂ or MgF₂ Substrate)
- Dynamics (FMR) – **Damping Divergence due to Nanoscale Disorder**

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